## **IN THE SPECIFICATION**

Please replace the paragraph beginning at page 8, line 18, with the following rewritten paragraph:

In particular, by containing [[Si]] Ce as the luminescent center ion in the host material thereof, the phosphor composed of the host material containing [[Si]] Ce of the present invention tends to show a high emission intensity as well as a small temperature quenching and, therefore, a less change in emission intensity with temperature change. Accordingly, the phosphor of the present invention can be effectively prevented from suffering from deterioration in brightness thereof with temperature rise of apparatuses when applied to displays or lighting systems.

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